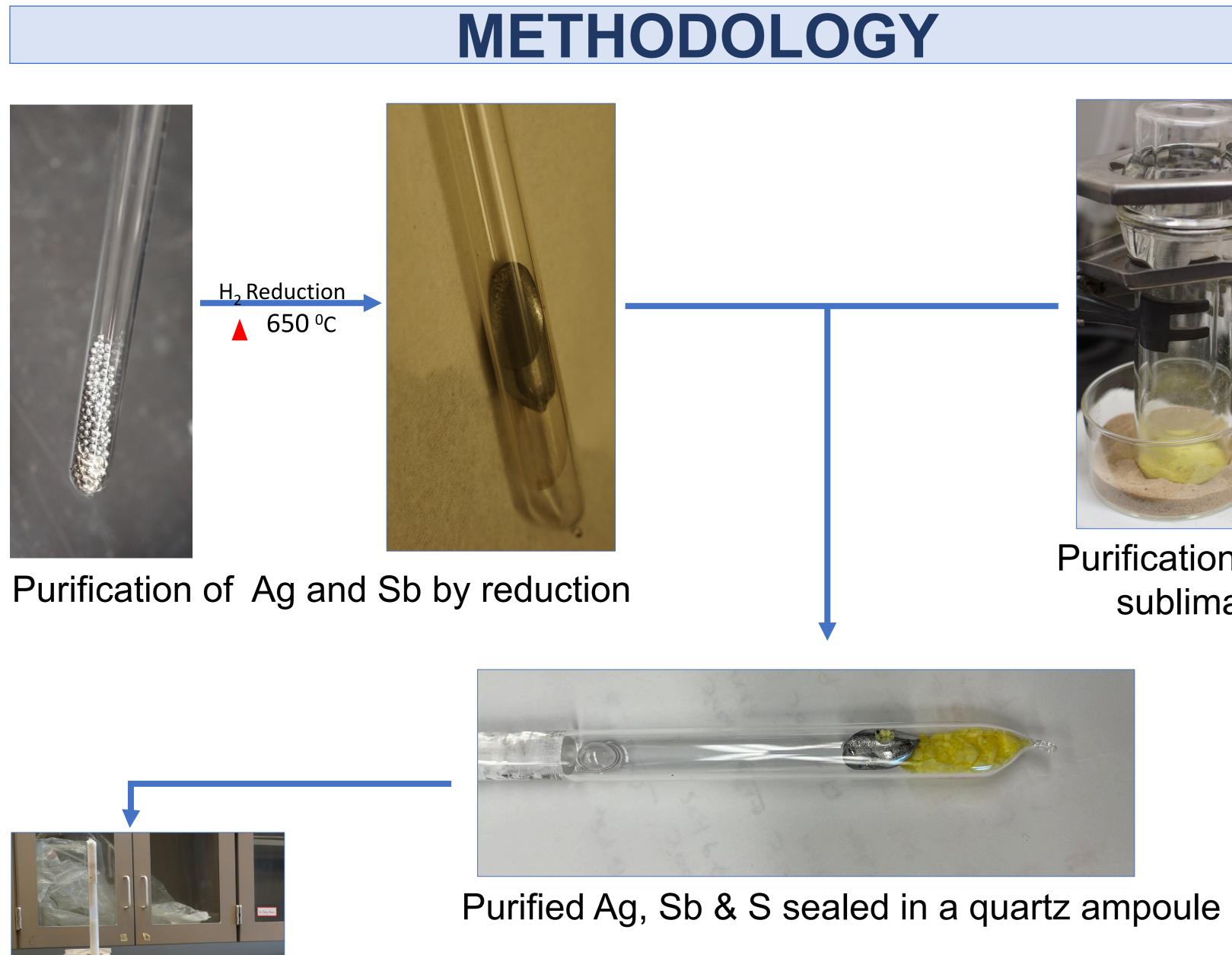


# **Growth of AgSbS<sub>2</sub> Single Crystals for Radiation Detector Applications** Venika Ekanayake<sup>1</sup>, Matthew Webster<sup>1</sup>, Manipaul Dhillon<sup>2</sup>, and Peng Wang<sup>1</sup> <sup>1</sup>Department of Chemistry, Queen's University, Kingston, Ontario, Canada <sup>2</sup>Department of Chemistry, University of British Columbia, Vancouver, British Colombia, Canada

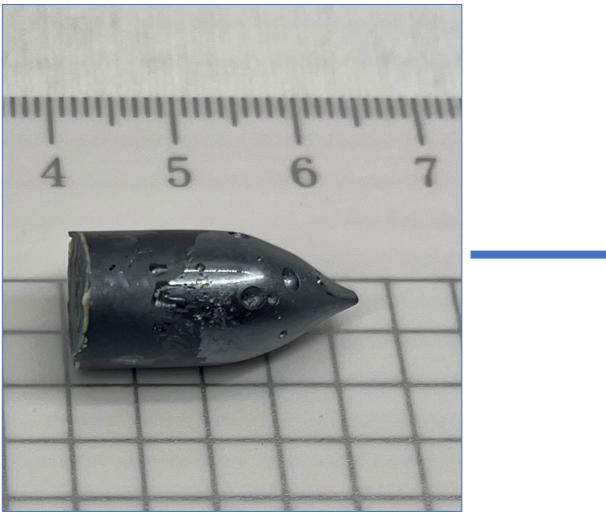
## INTRODUCTION

In medical imaging, nuclear safety, intelligence, and security applications, there is a high demand for room-temperature radiation detectors. A desirable radiation detection material must exhibit high sensitivity to radiation, high density, and a suitable band gap. Silver antimony sulfide (AgSbS<sub>2</sub>) is an emerging ternary semiconductor material used in photovoltaics, optoelectronics, and radiation detector applications. As a non-toxic and environmentally friendly semiconductor, AgSbS<sub>2</sub> adheres to principles of sustainable and safer chemical practices. With a bandgap ( $E_9$ ) of 1.7 eV, it offers higher chemical stability, sufficient hardness to stop radiation, and ease of synthesis, making it a promising sustainable alternative.

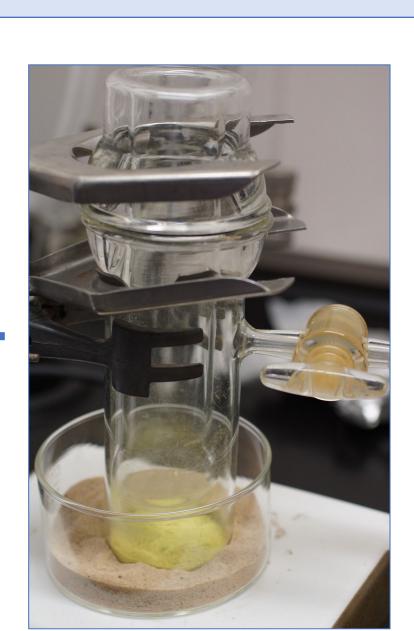




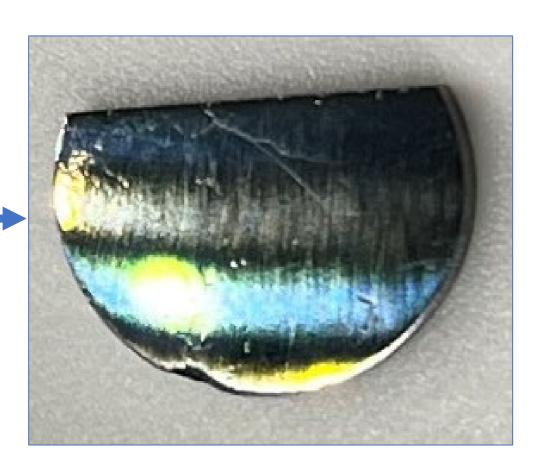
Growth of single crystal in vertical Bridgman furnace



AgSbS<sub>2</sub> Ingot



Purification of S by sublimation



Polished single crystal wafer

